



3.3V CMOS SINGLE POSITIVE-EDGE-TRIGGERED D-TYPE FLIP-FLOP

IDT74ALVC1G79

FEATURES:

- 0.5 MICRON CMOS Technology
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- 0.65mm pitch PSOP package
- Extended commercial range of - 40°C to + 85°C
- V_{CC} = 3.3V ± 0.3V, Normal Range
- V_{CC} = 1.65V to 3.6V, Extended Range
- V_{CC} = 2.5V ± 0.2V
- CMOS power levels (0.4µW typ. static)
- Rail-to-Rail output swing for increased noise margin

Drive Features for ALVC1G79:

- High Output Drivers: ±24mA
- Suitable for heavy loads

DESCRIPTION:

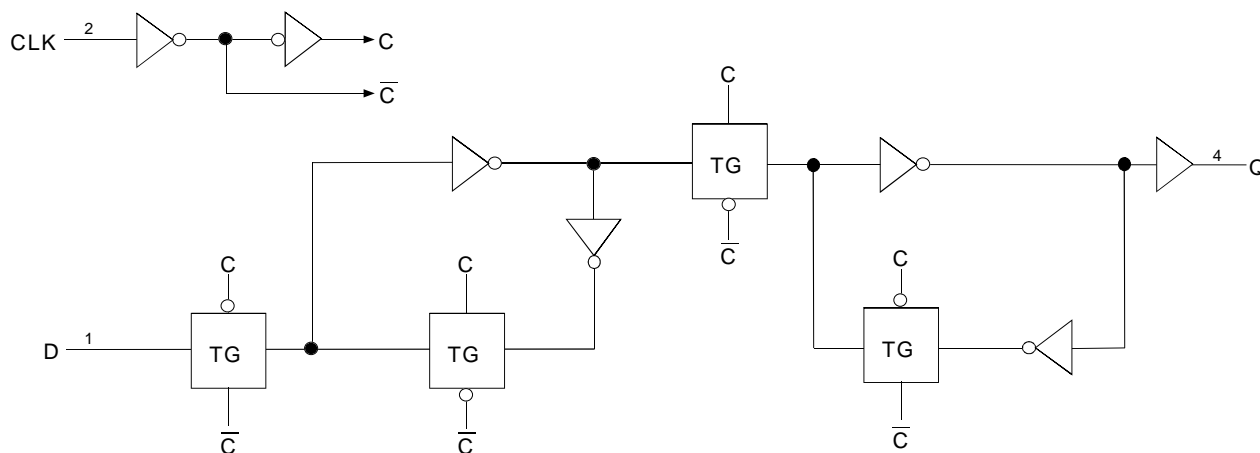
This single positive-edge-triggered D-type flip-flop is built using advanced dual metal CMOS technology. The ALVC1G79 is designed for 1.65V to 3.6V V_{CC} operation. When data at the data (D) input meets the setup time requirement, the data is transferred to the Q output on the positive-going edge of the clock pulse. Clock triggering occurs at a voltage level and is not directly related to the rise time of the clock pulse. Following the hold-time interval, data at the D input may be changed without affecting the levels at the outputs.

The ALVC1G79 has been designed with a ±24mA output driver. This driver is capable of driving a moderate to heavy load while maintaining speed performance.

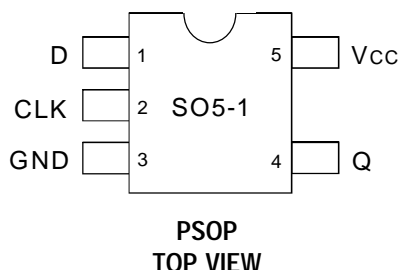
APPLICATIONS:

- 3.3V High Speed Systems
- 3.3V and lower voltage computing systems

FUNCTIONAL BLOCK DIAGRAM



PIN CONFIGURATION



PIN DESCRIPTION

Pin Names	Description
CLK	Clock Input
D	Data Input
Q	Data Output

FUNCTION TABLE (1)

Inputs		Output
CLK	D	Q
↑	H	H
↑	L	L
L	X	Q ₀

NOTE:

- H = HIGH Voltage Level
L = LOW Voltage Level
X = Don't Care
– = LOW-to-HIGH Transition
Q₀ = Level of Q before the indicated steady-state input conditions were established.

ABSOLUTE MAXIMUM RATING (1)

Symbol	Description	Max.	Unit
V _{TERM} (2)	Terminal Voltage with Respect to GND	– 0.5 to + 4.6	V
V _{TERM} (3)	Terminal Voltage with Respect to GND	–0.5 to V _{CC} + 0.5	V
T _{STG}	Storage Temperature	– 65 to + 150	°C
I _{OUT}	DC Output Current	– 50 to + 50	mA
I _{IK}	Continuous Clamp Current, V _i < 0 or V _i > V _{CC}	± 50	mA
I _{OK}	Continuous Clamp Current, V _o < 0	– 50	mA
I _{CC}	Continuous Current through each V _{CC} or GND	± 100	mA

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CAPACITANCE (TA = +25°C, f = 1.0MHz)

Symbol	Parameter(1)	Conditions	Typ.	Max.	Unit
C _{IN}	Input Capacitance	V _{IN} = 0V	5	7	pF
C _{OUT}	Output Capacitance	V _{OUT} = 0V	7	9	pF
C _{I/O}	I/O Port Capacitance	V _{IN} = 0V	7	9	pF

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NOTE:

- As applicable to the device type.

NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- V_{CC} terminals.
- All terminals except V_{CC}.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: TA = – 40°C to +85°C, V_{CC} = 2.3V to 3.6V

Symbol	Parameter	Test Conditions		Min.	Typ.(1)	Max.	Unit
V _{IH}	Input HIGH Voltage Level	V _{CC} = 1.65V to 1.95V		0.65 x V _{CC}	—	—	V
		V _{CC} = 2.3V to 2.7V		1.7	—	—	
		V _{CC} = 2.7V to 3.6V		2	—	—	
V _{IL}	Input LOW Voltage Level	V _{CC} = 1.65V to 1.95V		—	—	0.35 x V _{CC}	V
		V _{CC} = 2.3V to 2.7V		—	—	0.7	
		V _{CC} = 2.7V to 3.6V		—	—	0.8	
I _{IH}	Input HIGH Current	V _{CC} = 3.6V	V _i = V _{CC}	—	—	± 5	μA
I _{IL}	Input LOW Current	V _{CC} = 3.6V	V _i = GND	—	—	± 5	
I _{OZH}	High Impedance Output Current (3-State Output pins)	V _{CC} = 3.6V	V _o = V _{CC}	—	—	± 10	μA
I _{OZL}			V _o = GND	—	—	± 10	μA
V _{IK}	Clamp Diode Voltage	V _{CC} = 2.3V, I _{IN} = – 18mA		—	– 0.7	– 1.2	V
V _H	Input Hysteresis	V _{CC} = 3.3V		—	100	—	mV
I _{CC1}	Quiescent Power Supply Current	V _{CC} = 3.6V		—	0.1	10	μA
I _{CC2}		V _{IN} = GND or V _{CC}					
I _{CC3}							
ΔI _{CC}	Quiescent Power Supply Current Variation	One input at V _{CC} – 0.6V, other inputs at V _{CC} or GND		—	—	750	μA

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NOTE:

- Typical values are at V_{CC} = 3.3V, +25°C ambient.

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Max.	Unit
VOH	Output HIGH Voltage	V _{CC} = 1.65V to 3.6V	I _{OH} = - 0.1mA	V _{CC} - 0.2	—	V
		V _{CC} = 1.65V	I _{OH} = - 4mA	1.2		
		V _{CC} = 2.3V	I _{OH} = - 6mA	2	—	
		V _{CC} = 2.3V	I _{OH} = - 12mA	1.7	—	
		V _{CC} = 2.7V		2.2	—	
		V _{CC} = 3.0V		2.4	—	
		V _{CC} = 3.0V	I _{OH} = - 24mA	2	—	
VOL	Output LOW Voltage	V _{CC} = 1.65V to 3.6V	I _{OL} = 0.1mA	—	0.2	V
		V _{CC} = 1.65V	I _{OL} = 4mA		0.45	
		V _{CC} = 2.3V	I _{OL} = 6mA	—	0.4	
			I _{OL} = 12mA	—	0.7	
		V _{CC} = 2.7V	I _{OL} = 12mA	—	0.4	
		V _{CC} = 3.0V	I _{OL} = 24mA	—	0.55	

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NOTE:

1. V_{IH} and V_{IL} must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate V_{CC} range. T_A = - 40°C to + 85°C.

OPERATING CHARACTERISTICS, T_A = 25°C

Symbol	Parameter	Test Conditions	V _{CC} = 1.8V ± 0.15V	V _{CC} = 2.5 ± 0.2V	V _{CC} = 3.3V ± 0.3V	Unit
			Typ.	Typ.	Typ.	
CPD	Power Dissipation Capacitance	CL = 0pF, f = 10MHz	—	—	—	pF

SWITCHING CHARACTERISTICS⁽¹⁾

Symbol	Parameter	V _{CC} = 1.8V ± 0.15V		V _{CC} = 2.5V ± 0.2V		V _{CC} = 2.7V		V _{CC} = 3.3V ± 0.3V		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
f _{MAX}		—	—	—	—	—	—	—	—	MHz
t _P LH	Propagation Delay	—	12	—	6	—	5	—	3.8	ns
t _P HL	CLK to Q									
t _w	Pulse Width, CLK HIGH or LOW	5	—	3.3	—	3.3	—	3.3	—	ns
t _{SU}	Setup Time, data before CLK↑, HIGH	5	—	3	—	3	—	3	—	ns
t _{SU}	Setup Time, data before CLK↑, LOW	5	—	3	—	3	—	3	—	ns
t _H	Hold Time, data after CLK↑	2	—	1	—	1	—	0	—	ns

NOTE:

1. See test circuits and waveforms. T_A = - 40°C to + 85°C.

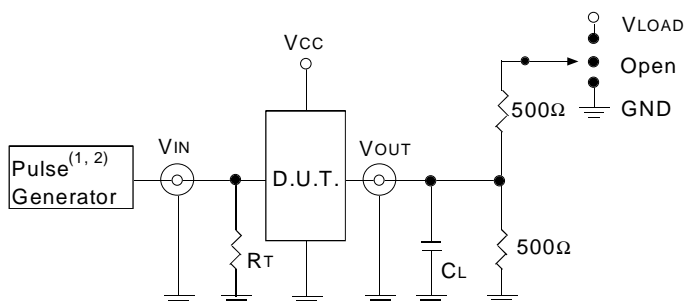
TEST CIRCUITS AND WAVEFORMS:

TEST CONDITIONS

Symbol	V _{CC} (1) = 3.3V ± 0.3V	V _{CC} (1) = 2.7V	V _{CC} (2) = 2.5V ± 0.2V	Unit
V _{LOAD}	6	6	2 x V _{CC}	V
V _{IH}	2.7	2.7	V _{CC}	V
V _T	1.5	1.5	V _{CC} / 2	V
V _{LZ}	300	300	150	mV
V _{HZ}	300	300	150	mV
C _L	50	50	30	pF

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TEST CIRCUITS FOR ALL OUTPUTS



DEFINITIONS:

C_L = Load capacitance: includes jig and probe capacitance.

R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

NOTES:

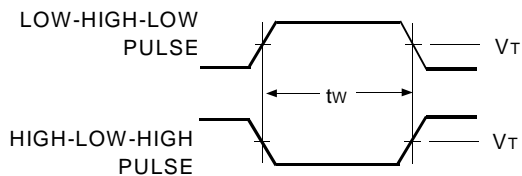
1. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_F ≤ 2.5ns; t_R ≤ 2.5ns.
2. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_F ≤ 2ns; t_R ≤ 2ns.

SWITCH POSITION

Test	Switch
Open Drain Disable Low Enable Low	V _{LOAD}
Disable High Enable High	GND
All Other tests	Open

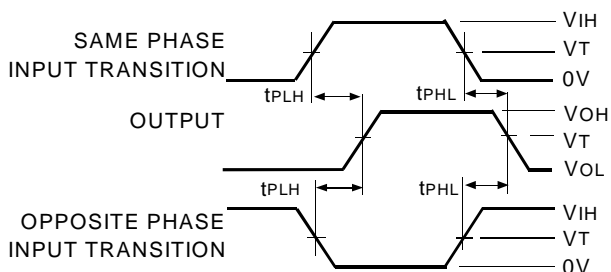
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PULSE WIDTH



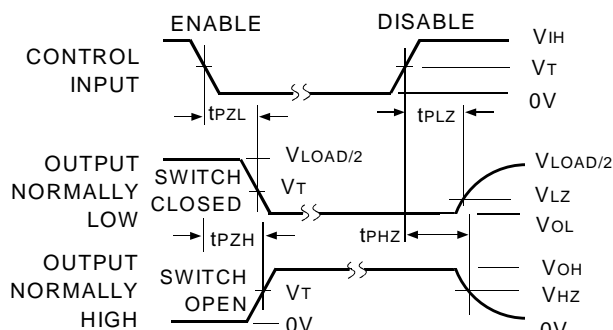
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PROPAGATION DELAY



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ENABLE AND DISABLE TIMES

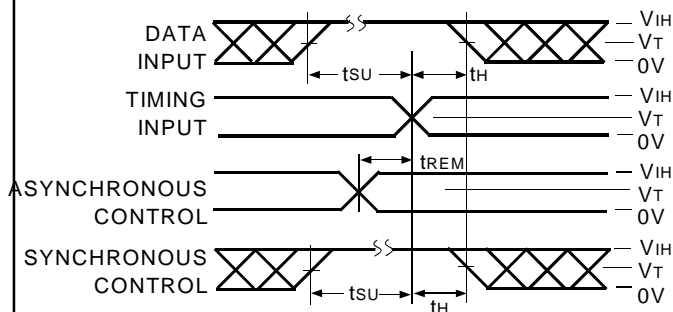


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NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

SET-UP, HOLD, AND RELEASE TIMES



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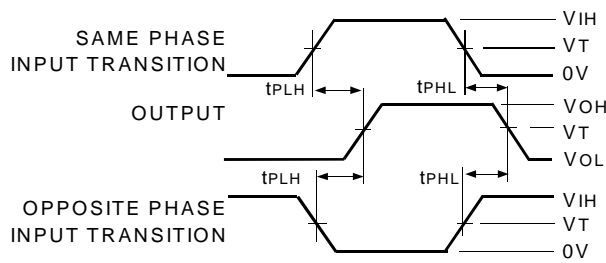
1.8V ± 0.15V TEST CIRCUITS AND WAVEFORMS:

TEST CONDITIONS

Symbol	V _{CC} (1) = 1.8V ± 0.15V	Unit
V _{LOAD}	2 x V _{CC}	V
V _{IH}	V _{CC}	V
V _T	V _{CC} / 2	V
V _{LZ}	150	mV
V _{HZ}	150	mV
C _L	30	pF

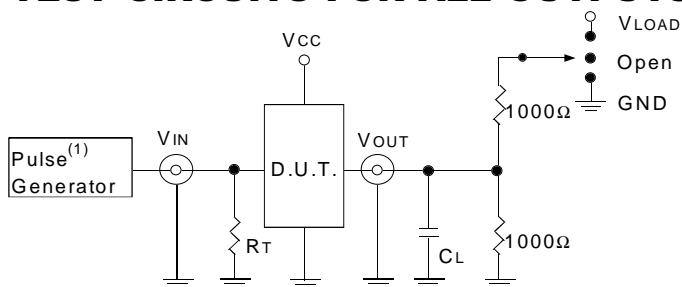
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PROPAGATION DELAY



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TEST CIRCUITS FOR ALL OUTPUTS



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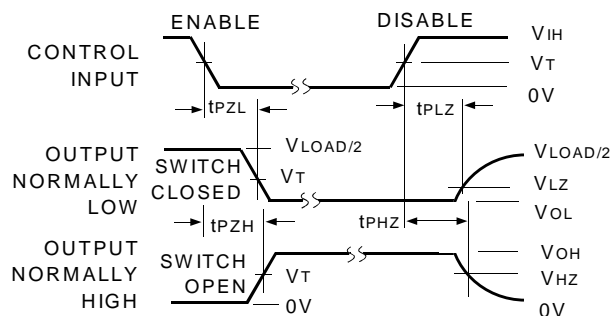
DEFINITIONS:

C_L = Load capacitance: includes jig and probe capacitance.
R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

NOTE:

1. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_f ≤ 2ns; t_r ≤ 2ns.

ENABLE AND DISABLE TIMES



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NOTE:

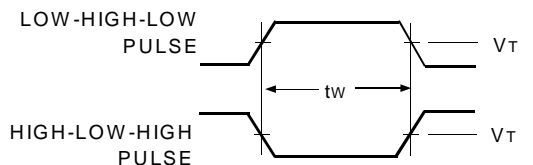
1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

SWITCH POSITION

Test	Switch
Open Drain Disable Low Enable Low	V _{LOAD}
Disable High Enable High	GND
All Other tests	Open

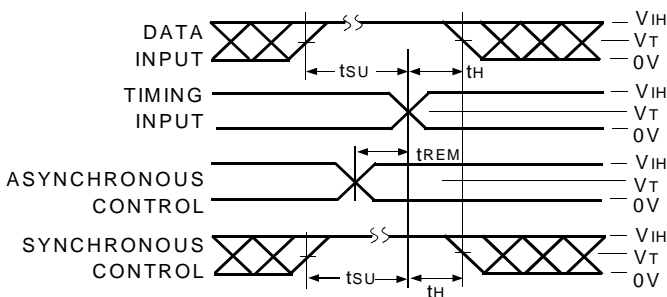
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PULSE WIDTH



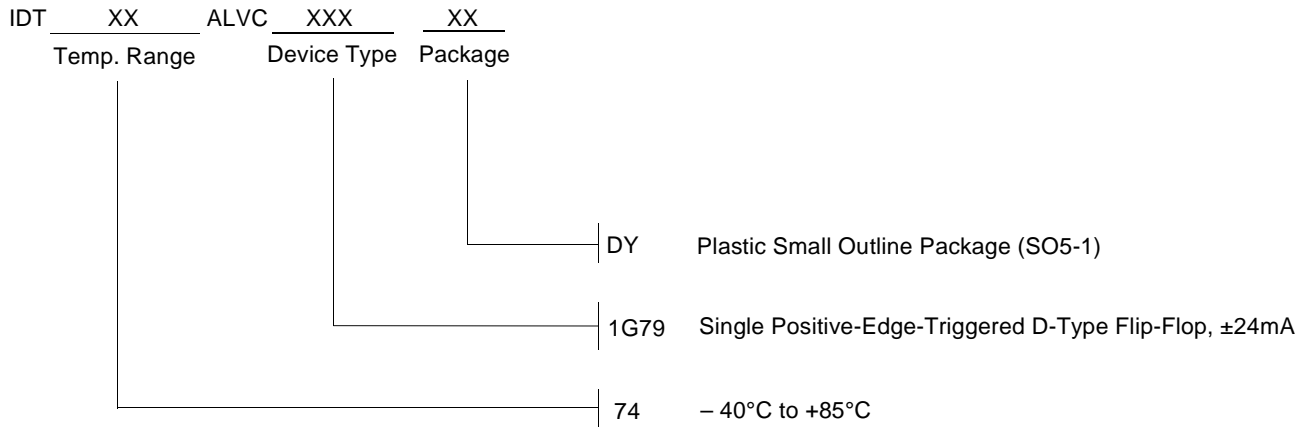
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SET-UP, HOLD, AND RELEASE TIMES



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ORDERING INFORMATION



PICOLOGIC-LOGIC (DY) PACKAGES

Due to their small size, PicoGate-Logic packages require more complex symbolization guidelines. IDT's 5-pin PSOP (DY) packaged devices utilize a three-symbol name rule. The first symbol denotes device technology, the second symbol denotes device function, and the third symbol denotes a wafer fab/assembly site code for internal tracking.

EXAMPLES:

1. A PicoGate-Logic device with package code LR* is an IDT74LVC1G79A.
2. A PicoGate-Logic device with package code GC* is an IDT74ALVC1G04.

PICOLOGIC-LOGIC (DY) PACKAGE SYMBOLIZATION GUIDELINES

TECHNOLOGY	CODE	FUNCTION	CODE
ALVC	G	00	A
ALVCH	J	02	B
LVC	L	04	C
LVCH ⁽¹⁾		U04	D
		06	T
		07	V
		08	E
		14	F
		32	G
		79	R
		86	H
		125	M
		126	N
		132	Y

NOTE:

1. Code to be determined.



CORPORATE HEADQUARTERS
2975 Stender Way
Santa Clara, CA 95054

for SALES:
800-345-7015 or 408-727-6116
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